LM741 Operational Amplifier

General Description

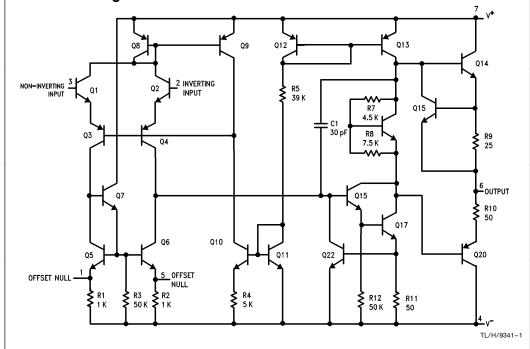
The LM741 series are general purpose operational amplifiers which feature improved performance over industry standards like the LM709. They are direct, plug-in replacements for the 709C, LM201, MC1439 and 748 in most applications.

The amplifiers offer many features which make their application nearly foolproof: overload protection on the input and

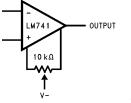
output, no latch-up when the common mode range is exceeded, as well as freedom from oscillations.

The LM741C/LM741E are identical to the LM741/LM741A except that the LM741C/LM741E have their performance guaranteed over a 0°C to +70°C temperature range, instead of -55°C to +125°C.

Schematic Diagram



Offset Nulling Circuit



TL/H/9341-7

Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications. (Note 5)

,	LM741A	LM741E	LM741	LM741C
Supply Voltage	$\pm22V$	$\pm22V$	$\pm22V$	$\pm18V$
Power Dissipation (Note 1)	500 mW	500 mW	500 mW	500 mW
Differential Input Voltage	$\pm 30 V$	$\pm 30V$	$\pm30V$	$\pm 30 V$
Input Voltage (Note 2)	$\pm15V$	$\pm15V$	$\pm15V$	$\pm15V$
Output Short Circuit Duration	Continuous	Continuous	Continuous	Continuous
Operating Temperature Range	-55°C to $+125^{\circ}\text{C}$	0°C to +70°C	-55°C to $+125^{\circ}\text{C}$	0°C to +70°C
Storage Temperature Range	$-65^{\circ}\text{C to } + 150^{\circ}\text{C}$	$-65^{\circ}\text{C to} + 150^{\circ}\text{C}$	$-65^{\circ}\text{C to } + 150^{\circ}\text{C}$	-65°C to $+150^{\circ}\text{C}$
Junction Temperature	150°C	100°C	150°C	100°C
Soldering Information				
N-Package (10 seconds)	260°C	260°C	260°C	260°C
J- or H-Package (10 seconds)	300°C	300°C	300°C	300°C
M-Package				
Vapor Phase (60 seconds)	215°C	215°C	215°C	215°C
Infrared (15 seconds)	215°C	215°C	215°C	215°C
0 111 150 110 1 11 11 11		5 5		

See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.

ESD Tolerance (Note 6) 400V 400V 400V 400V

Electrical Characteristics (Note 3)

Parameter	Conditions	LM741A/LM741E LM74		LM741		LM741C			Units		
Parameter	Conditions	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Oilles
Input Offset Voltage	$\begin{aligned} T_{A} &= 25^{\circ}C \\ R_{S} &\leq 10 \text{ k}\Omega \\ R_{S} &\leq 50\Omega \end{aligned}$		0.8	3.0		1.0	5.0		2.0	6.0	mV mV
	$\begin{aligned} &T_{AMIN} \leq T_{A} \leq T_{AMAX} \\ &R_{S} \leq 50\Omega \\ &R_{S} \leq 10 \ k\Omega \end{aligned}$			4.0			6.0			7.5	mV mV
Average Input Offset Voltage Drift				15							μV/°C
Input Offset Voltage Adjustment Range	$T_A = 25^{\circ}C, V_S = \pm 20V$	±10				± 15			±15		mV
Input Offset Current	$T_A = 25^{\circ}C$		3.0	30		20	200		20	200	nA
	$T_{AMIN} \leq T_{A} \leq T_{AMAX}$			70		85	500			300	nA
Average Input Offset Current Drift				0.5							nA/°C
Input Bias Current	$T_A = 25^{\circ}C$		30	80		80	500		80	500	nA
	$T_{AMIN} \le T_A \le T_{AMAX}$			0.210			1.5			0.8	μΑ
Input Resistance	$T_A = 25^{\circ}C, V_S = \pm 20V$	1.0	6.0		0.3	2.0		0.3	2.0		$M\Omega$
	$T_{AMIN} \le T_A \le T_{AMAX},$ $V_S = \pm 20V$	0.5									МΩ
Input Voltage Range	$T_A = 25^{\circ}C$							±12	±13		V
	$T_{AMIN} \le T_A \le T_{AMAX}$				±12	±13					V
Large Signal Voltage Gain	$ \begin{array}{l} T_A = 25^{\circ} C, R_L \geq 2 k\Omega \\ V_S = \pm 20V, V_O = \pm 15V \\ V_S = \pm 15V, V_O = \pm 10V \end{array} $	50			50	200		20	200		V/mV V/mV
	$\begin{split} &T_{AMIN} \leq T_{A} \leq T_{AMAX}, \\ &R_{L} \geq 2 k\Omega, \\ &V_{S} = \pm 20V, V_{O} = \pm 15V \\ &V_{S} = \pm 15V, V_{O} = \pm 10V \end{split}$	32			25			15			V/mV V/mV
	$V_S = \pm 5V, V_O = \pm 2V$	10									V/mV

Electrical Characteristics (Note 3) (Continued)

Parameter	Conditions	LM741A/LM741E			LM741			LM741C			Units
raiametei	Conditions	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Oilles
Output Voltage Swing	$\begin{aligned} V_{S} &= \pm 20V \\ R_{L} &\geq 10 k\Omega \\ R_{L} &\geq 2 k\Omega \end{aligned}$	±16 ±15									V
	$\begin{aligned} V_{S} &= \pm 15 V \\ R_{L} &\geq 10 k\Omega \\ R_{L} &\geq 2 k\Omega \end{aligned}$				±12 ±10	±14 ±13		±12 ±10	±14 ±13		\ \ \
Output Short Circuit Current	$T_A = 25^{\circ}C$ $T_{AMIN} \le T_A \le T_{AMAX}$	10 10	25	35 40		25			25		mA mA
Common-Mode Rejection Ratio	$\begin{split} & T_{AMIN} \leq T_A \leq T_{AMAX} \\ & R_S \leq 10 \ k\Omega, \ V_{CM} = \ \pm 12V \\ & R_S \leq 50\Omega, \ V_{CM} = \ \pm 12V \end{split}$	80	95		70	90		70	90		dB dB
Supply Voltage Rejection Ratio	$\begin{aligned} & T_{AMIN} \leq T_A \leq T_{AMAX}, \\ & V_S = \pm 20 \text{V to } V_S = \pm 5 \text{V} \\ & R_S \leq 50 \Omega \\ & R_S \leq 10 \text{ k} \Omega \end{aligned}$	86	96		77	96		77	96		dB dB
Transient Response Rise Time Overshoot	T _A = 25°C, Unity Gain		0.25 6.0	0.8 20		0.3 5			0.3 5		μs %
Bandwidth (Note 4)	T _A = 25°C	0.437	1.5								MHz
Slew Rate	T _A = 25°C, Unity Gain	0.3	0.7			0.5			0.5		V/μs
Supply Current	T _A = 25°C					1.7	2.8		1.7	2.8	mA
Power Consumption	$T_A = 25^{\circ}C$ $V_S = \pm 20V$ $V_S = \pm 15V$		80	150		50	85		50	85	mW mW
LM741A	$V_S = \pm 20V$ $T_A = T_{AMIN}$ $T_A = T_{AMAX}$			165 135							mW mW
LM741E	$V_S = \pm 20V$ $T_A = T_{AMIN}$ $T_A = T_{AMAX}$			150 150							mW mW
LM741	$V_S = \pm 15V$ $T_A = T_{AMIN}$ $T_A = T_{AMAX}$					60 45	100 75				mW mW

Note 1: For operation at elevated temperatures, these devices must be derated based on thermal resistance, and T_j max. (listed under "Absolute Maximum Ratings"), $T_j = T_A + (\theta_{jA} P_D)$.

Thermal Resistance	Cerdip (J)	DIP (N)	HO8 (H)	SO-8 (M)
θ_{jA} (Junction to Ambient)	100°C/W	100°C/W	170°C/W	195°C/W
$\theta_{ m jC}$ (Junction to Case)	N/A	N/A	25°C/W	N/A

Note 2: For supply voltages less than \pm 15V, the absolute maximum input voltage is equal to the supply voltage.

Note 3: Unless otherwise specified, these specifications apply for $V_S = \pm 15V$, $-55^{\circ}C \le T_A \le +125^{\circ}C$ (LM741/LM741A). For the LM741C/LM741E, these specifications are limited to $0^{\circ}C \le T_A \le +70^{\circ}C$.

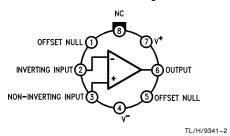
Note 4: Calculated value from: BW (MHz) = 0.35/Rise Time(μ s).

Note 5: For military specifications see RETS741X for LM741 and RETS741AX for LM741A.

Note 6: Human body model, 1.5 k Ω in series with 100 pF.

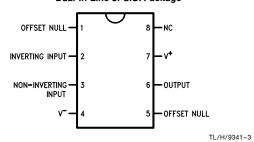
Connection Diagrams

Metal Can Package



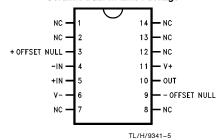
Order Number LM741H, LM741H/883*, LM741AH/883 or LM741CH See NS Package Number H08C

Dual-In-Line or S.O. Package



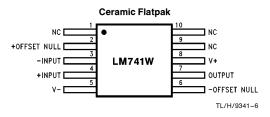
Order Number LM741J, LM741J/883, LM741CM, LM741CN or LM741EN See NS Package Number J08A, M08A or N08E

Ceramic Dual-In-Line Package



Order Number LM741J-14/883*, LM741AJ-14/883** See NS Package Number J14A

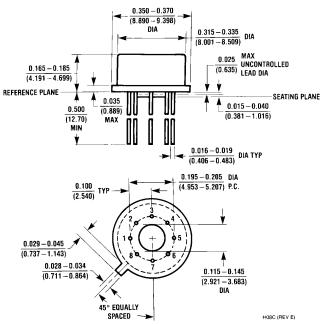
*also available per JM38510/10101
**also available per JM38510/10102



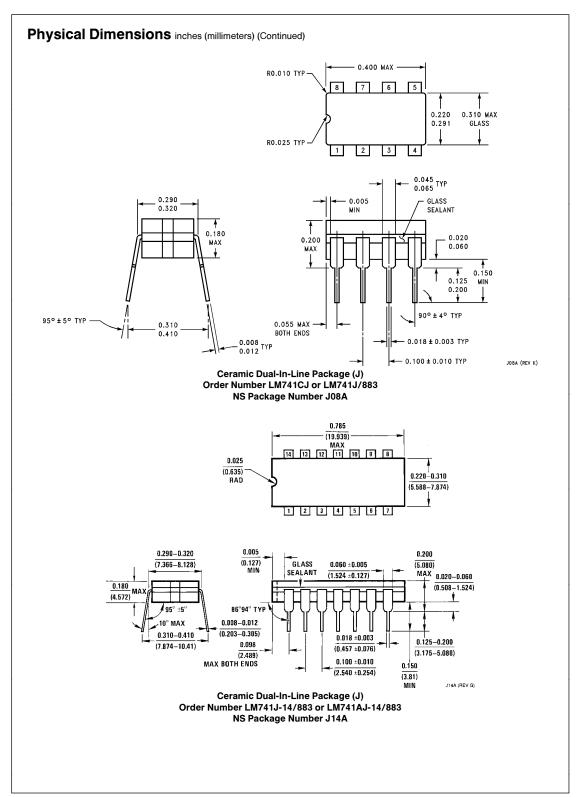
Order Number LM741W/883 See NS Package Number W10A

^{*}LM741H is available per JM38510/10101

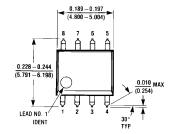


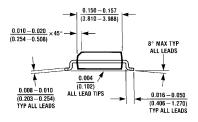


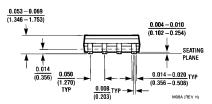
Metal Can Package (H)
Order Number LM741H, LM741H/883, LM741AH/883, LM741CH or LM741EH
NS Package Number H08C



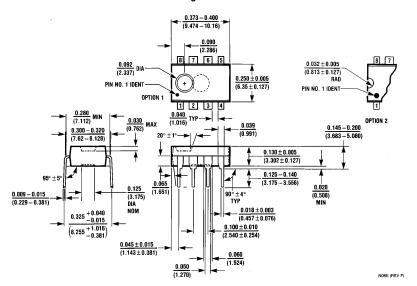






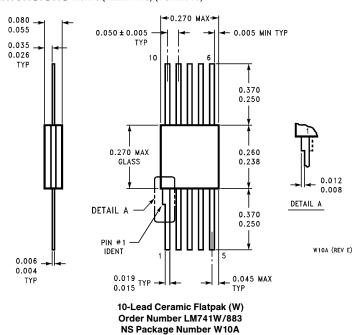


Small Outline Package (M) Order Number LM741CM NS Package Number M08A



Dual-In-Line Package (N) Order Number LM741CN or LM741EN NS Package Number N08E

Physical Dimensions inches (millimeters) (Continued)



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